



Jang kyounggho

(Tokyo Electron Korea / Republic of Korea)

I completed my bachelor's degree ('94) and master's degree ('99) in chemistry at Hanyang University and joined Samsung Electronics to work on plasma patterning.

I also carried out the development of semiconductor equipment and new processes accordingly and participated in the development of many memory products (DRAM, Flash, SRAM, etc.).

In addition, I also carried out material development and process application for the recently highlighted CN (CO2 Net zero) project.

From the end of 2021, I have joined Tokyo Electron Korea to help customer's product development.